MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage (from V _{CC} to V _{EE})	V _S	40	V
Input Differential Voltage Range	V _{IDR}	Note 1	V
Input Voltage Range	V _{IR}	Note 1	V
Junction Temperature (Note 2)	TJ	+150	°C
Operating Temperature Range	T _A	-40 to +125	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C
DC Output Current	I _O	1.0	Α
Peak Output Current (Nonrepetitive)	I _(max)	1.5	А
Thermal Resistance, Junction-to-Air Case 626 Case 648 Case 751G	$R_{ heta JA}$	137 72 80	°C/W
Thermal Resistance, Junction-to-Case Case 626 Case 648 Case 751G	R _{θJC}	23 10 12	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Either or both input voltages should not exceed the magnitude of V_{CC} or V_{EE}.

2. Power dissipation must be considered to ensure maximum junction temperature (T_J) is not exceeded.

DC ELECTRICAL CHARACTERISTICS (V_{CC} = +15 V, V_{EE} = -15 V, R_L connected to ground, T_A = -40° to +125°C.)

Characteristics	Symbol	Min	Тур	Max	Unit
Input Offset Voltage (V _{CM} = 0)	V _{IO}				mV
$T_A = +25^{\circ}C$		_	1.0	15	
T_A , T_{low} to T_{high}		_	_	20	
Average Temperature Coefficient of Offset Voltage	$\Delta V_{IO}/\Delta T$	_	20	-	μV/°C
Input Bias Current (V _{CM} = 0)	I _{IB}	_	100	500	nA
Input Offset Current (V _{CM} = 0)	I _{IO}	_	10	50	nA
Large Signal Voltage Gain $V_O = \pm 10 \text{ V}, R_L = 2.0 \text{ k}$	A _{VOL}	30	100	-	V/mV
Output Voltage Swing ($I_L = 100 \text{ mA}$) $T_{\Delta} = +25^{\circ}\text{C}$	V _{OH}	14.0	14.2		V
$T_A = +23$ C $T_A = T_{low} \text{ to } T_{high}$		13.9	14.2	_	
$T_A = +25$ °C	V _{OL}	-	-14.2	-14.0	
$T_A = T_{low}$ to T_{high}	OL OL	_	_	-13.9	
Output Voltage Swing (I _L = 1.0 A)	V _{OH}				V
$V_{CC} = +24 \text{ V}, V_{EE} = 0 \text{ V}, T_A = +25^{\circ}\text{C}$		22.5	22.7	_	
$V_{CC} = +24 \text{ V}, V_{EE} = 0 \text{ V}, T_A = T_{low} \text{ to } T_{high}$		22.5	-	-	
$V_{CC} = +24 \text{ V}, V_{EE} = 0 \text{ V}, T_A = +25^{\circ}\text{C}$	V _{OL}	_	1.3	1.5 1.5	
$V_{CC} = +24 \text{ V}, V_{EE} = 0 \text{ V}, T_A = T_{low} \text{ to } T_{high}$		_	_	1.5	
Input Common Mode Voltage Range	V_{ICR}	.,			V
$T_A = +25^{\circ}C$		V _{EE} to (V _{CC} -1.0)			
$T_A = T_{low}$ to T_{high}			to (V _{CC} –	1.3)	
Common Mode Rejection Ratio (R _S = 10 k)	CMRR	70	90	_	dB
Power Supply Rejection Ratio ($R_S = 100 \Omega$)	PSRR	70	90	_	dB
Power Supply Current	I _D				mA
$T_A = +25^{\circ}C$ TCA0372		_	5.0	10	
TCA0372B		_	8.0	10	
$T_A = T_{low}$ to T_{high} TCA0372		_	_	14	
TCA0372B		_	_	14	

$\textbf{AC ELECTRICAL CHARACTERISTICS} \ (V_{CC} = +15 \ \text{V}, \ V_{EE} = -15 \ \text{V}, \ R_L \ connected \ to \ ground}, \ T_A = +25 ^{\circ}\text{C}, \ unless \ otherwise \ noted.)$

Characteristics	Symbol	Min	Тур	Max	Unit
Slew Rate (V_{in} = -10 V to +10 V, R_L = 2.0 k, C_L = 100 pF) A_V = -1.0, T_A = T_{low} to T_{high}	SR	1.0	1.4	-	V/μs
Gain Bandwidth Product (f = 100 kHz, C_L = 100 pF, R_L = 2.0 k) T_A = 25°C T_A = T_{low} to T_{high}	GBW	0.9 0.7	1.4 -	1 1	MHz
Phase Margin $T_J = T_{low}$ to T_{high} $R_L = 2.0 \text{ k}, C_L = 100 \text{ pF}$	Фт	_	65	-	Degrees
Gain Margin $R_L = 2.0 \text{ k}, C_L = 100 \text{ pF}$	A _m	-	15	-	dB
Equivalent Input Noise Voltage $R_S = 100 \Omega$, $f = 1.0 to 100 kHz$	e _n	-	22	-	nV/√Hz
Total Harmonic Distortion $A_V = -1.0$, $R_L = 50 \Omega$, $V_O = 0.5$ VRMS, $f = 1.0$ kHz	THD	_	0.02	_	%

NOTE: In case V_{EE} is disconnected before V_{CC}, a diode between V_{EE} and Ground is recommended to avoid damaging the device.

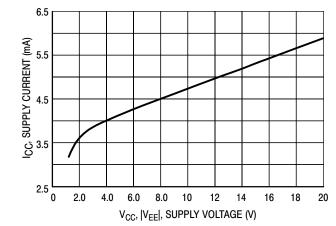


Figure 2. Supply Current versus Supply Voltage with No Load

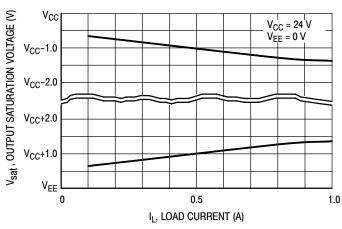


Figure 3. Output Saturation Voltage versus Load Current

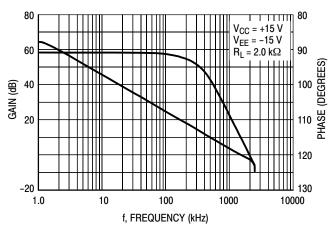


Figure 4. Voltage Gain and Phase versus Frequency

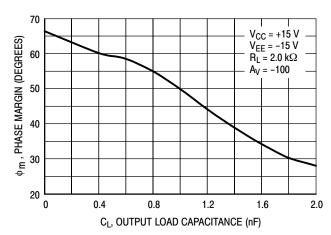


Figure 5. Phase Margin versus Output Load Capacitance

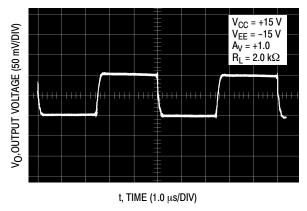


Figure 6. Small Signal Transient Response

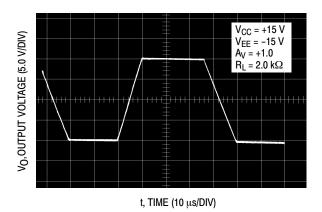


Figure 7. Large Signal Transient Response

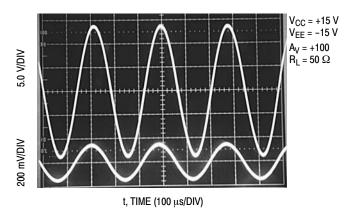


Figure 8. Sine Wave Response

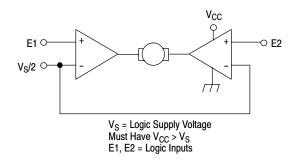
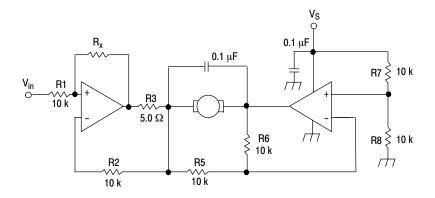


Figure 9. Bidirectional DC Motor Control with Microprocessor-Compatible Inputs



For circuit stability, ensure that $R_X > \frac{2R3 + R1}{R_M}$ where, R_M = internal resistance of motor. The voltage available at the terminals of the motor is: $V_M = 2 \left(V_1 - \frac{V_S}{2}\right) + |R_0| \cdot I_M$ where, $|R_0| = \frac{2R3 \cdot R1}{R_X}$ and I_M is the motor current.

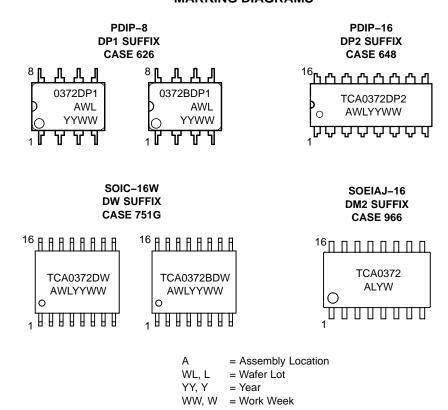
Figure 10. Bidirectional Speed Control of DC Motors

ORDERING INFORMATION

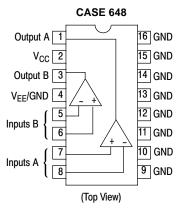
Device	Package	Shipping [†]
TCA0372DW	SOIC-16W	47 Units / Rail
TCA0372DWG	SOIC-16W (Pb-Free)	47 Units / Rail
TCA0372DWR2	SOIC-16W	1000 Tape & Reel
TCA0372DWR2G	SOIC-16W (Pb-Free)	1000 Tape & Reel
TCA0372BDWR2	SOIC-16W	1000 Tape & Reel
TCA0372BDWR2G	SOIC-16W (Pb-Free)	1000 Tape & Reel
TCA0372DP1	PDIP-8	50 Units / Rail
TCA0372DP1G	PDIP-8 (Pb-Free)	50 Units / Rail
TCA0372BDP1	PDIP-8	50 Units / Rail
TCA0372BDP1G	PDIP-8 (Pb-Free)	50 Units / Rail
TCA0372DP2	PDIP-16	25 Units / Rail
TCA0372DP2G	PDIP-16 (Pb-Free)	25 Units / Rail
TCA0372DM2EL	SOEIAJ-16	2500 Tape & Reel
TCA0372DM2ELG	SOEIAJ-16 (Pb-Free)	2500 Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

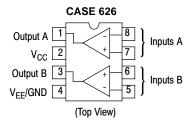
MARKING DIAGRAMS

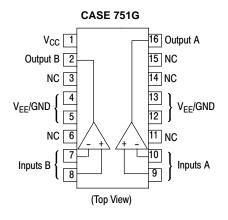


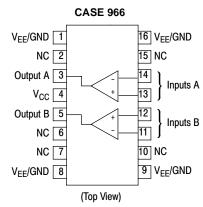
PIN CONNECTIONS



*Pins 4 and 9 to 16 are internally connected.

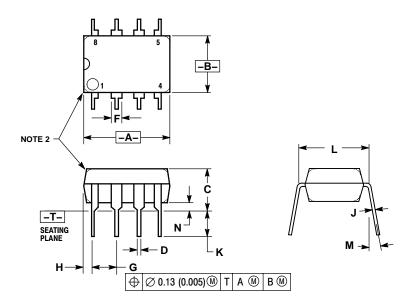






PACKAGE DIMENSIONS

PDIP-8 **DP1 SUFFIX** CASE 626-05 ISSUE L



- NOTES:

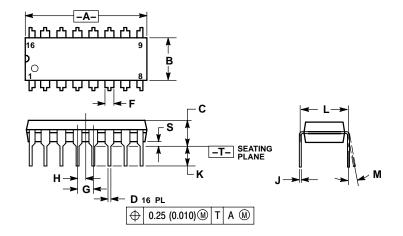
 1. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.

 2. PACKAGE CONTOUR OPTIONAL (ROUND OR
- SQUARE CORNERS).

 3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	9.40	10.16	0.370	0.400
В	6.10	6.60	0.240	0.260
С	3.94	4.45	0.155	0.175
D	0.38	0.51	0.015	0.020
F	1.02	1.78	0.040	0.070
G	2.54 BSC		0.100 BSC	
Н	0.76	1.27	0.030	0.050
J	0.20	0.30	0.008	0.012
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300	BSC
M		10°		10°
N	0.76	1 01	0.030	0.040

PDIP-16 **DP2 SUFFIX** CASE 648-08 ISSUE T

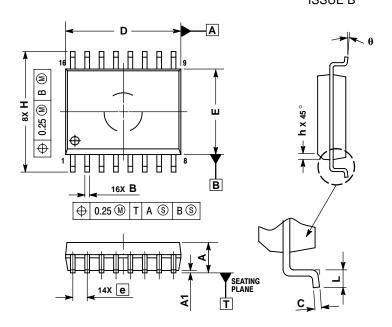


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 5. ROUNDED CORNERS OPTIONAL.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.740	0.770	18.80	19.55
В	0.250	0.270	6.35	6.85
С	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100	BSC	2.54 BSC	
Н	0.050	BSC	1.27 BSC	
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
M	0°	10 °	0°	10 °
S	0.020	0.040	0.51	1.01

PACKAGE DIMENSIONS

SOIC-16W **DW SUFFIX** CASE 751G-03 **ISSUE B**



- NOTES:
 1. DIMENSIONS ARE IN MILLIMETERS.
 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
- DIMENSIONS D AND E DO NOT INLCUDE MOLD PROTRUSION.
- PROTRUSION.

 4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

 5. DIMENSION B DOES NOT INCLUDE DAMBAR

 PROTRUSION. ALLOWABLE DAMBAR

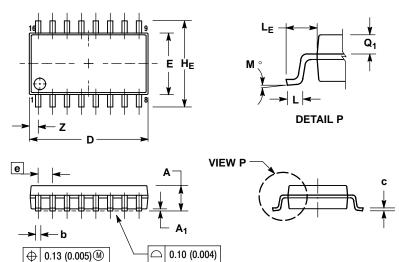
 PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS

 OF THE B DIMENSION AT MAXIMUM MATERIAL

 CONDITION.

	MILLIMETERS			
DIM	MIN	MAX		
Α	2.35	2.65		
A1	0.10	0.25		
В	0.35	0.49		
С	0.23	0.32		
D	10.15	10.45		
E	7.40	7.60		
е	1.27	BSC		
Н	10.05	10.55		
h	0.25	0.75		
Ĺ	0.50	0.90		
θ	0 °	7°		





NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI
- 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 4. TERMINAL NUMBERS ARE SHOWN FOR
- TERMINAL NUMBERS ARE SHOWN FOR THE REFERENCE ONLY.
 THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH
 DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE
 BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIMETERS		S INCHES	
DIM	MIN	MAX	MIN	MAX
Α		2.05		0.081
A ₁	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
C	0.18	0.27	0.007	0.011
D	9.90	10.50	0.390	0.413
Е	5.10	5.45	0.201	0.215
е	1.27 BSC		0.050 BSC	
HE	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
LΕ	1.10	1.50	0.043	0.059
M	0 °	10°	0 °	10°
Q1	0.70	0.90	0.028	0.035
Z		0.78		0.031

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